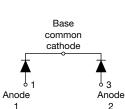
**Vishay Semiconductors** 

# **High Performance Schottky Rectifier New Generation 3** D-61 Package, 2 x 55 A

VS-110CNQ045APbF Base common cathode 62 3 Anode Anode Common 1 cathode 2 D-61-8 VS-110CNQ045ASMPbF ۶ d 2 Anode Common Anode cathode D-61-8-SM

#### VS-110CNQ045ASLPbF





Common cathode

54 mJ

**Diode variation** 

E<sub>AS</sub>

PRO

D-61-8-SL	
DUCT SUMMARY	
Package	D-61
I <sub>F(AV)</sub>	2 x 55 A
V <sub>R</sub>	45 V
V <sub>F</sub> at I <sub>F</sub>	0.54 V
I <sub>RM</sub> max.	350 mA at 125 °C
T <sub>J</sub> max.	150 °C

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### **FEATURES**

- 150 °C T<sub>J</sub> operation
- · Center tap module
- · Very low forward voltage drop
- High frequency operation
- High power discrete
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- · New fully transfer-mold low profile, small footprint, high current package
- · Designed and qualified for industrial level
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### Note

This datasheet provides information about parts that are RoHS-compliant and/or parts that are non-RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information/tables in this datasheet for details.

### DESCRIPTION

The center tap Schottky rectifier module has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES UI				
I <sub>F(AV)</sub>	Rectangular waveform	110	A			
V <sub>RRM</sub>		45	V			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	5400	А			
V <sub>F</sub>	55 $A_{pk}$ , $T_J$ = 125 °C (per leg)	0.5	V			
TJ	Range	-55 to +150	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-110CNQ045APbF	UNITS			
Maximum DC reverse voltage	V <sub>R</sub>	45	V			
Maximum working peak reverse voltage	V <sub>RWM</sub>	45	V			

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ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDI	VALUES	UNITS	
Maximum average forward current	per leg		E0.% duty avala at T = 125 °C	105 °C restangular waveform		A
See fig. 5	per device	IF(AV)	$I_{F(AV)}$ 50 % duty cycle at $T_C$ = 125 °C, rectangular waveform		110	
Maximum peak one cycle non-repetitive surge current per leg See fig. 7		I <sub>FSM</sub>	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	5400	A
			10 ms sine or 6 ms rect. pulse	rated V <sub>RRM</sub> applied	800	
Non-repetitive avalanche energy per leg		E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 8 A, L = 1.7 mH		54	mJ
Repetitive avalanche current per leg		I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu s$ Frequency limited by T_J maximum V_A = 1.5 x V_R typical		8	А

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS VAI			UNITS	
	V <sub>FM</sub> <sup>(1)</sup>	55 A	T - 25 °C	0.54	V	
Maximum forward voltage drop per leg See fig. 1		110 A	T <sub>J</sub> = 25 °C	0.7		
		55 A	T 105 %C	0.5		
		110 A	T <sub>J</sub> = 125 °C	0.69		
Maximum reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	3	mA	
See fig. 2		T <sub>J</sub> = 125 °C	V <sub>R</sub> = naleu V <sub>R</sub>	350		
Maximum junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		3800	pF	
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 mm from package body		5.5	nH	
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub> 10 000 V			V/µs	

### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55 to +150	°C	
Maximum thermal resistance, junction to case per leg		D	DC operation See fig. 4	0.5	°C/W	
Maximum thermal resistance, junction to case per package		R <sub>thJC</sub>	DC operation	0.25		
Typical thermal resistance, case to heatsink (D-61-8 only)		R <sub>thCS</sub>	Mounting surface, smooth and greased Device flatness < 5 mils	0.30		
				7.8	g	
Approximate weight	Approximate weight			0.28	oz.	
Mounting torque minimum (D-61-8 only) maximum				40 (35)	kgf ⋅ cm	
				58 (50)	(lbf · in)	
Marking device			Case style D-61	110CN0	2045A	
			Case style D-61-8-SM		45ASM	
			Case style D-61-8-SL	110CNQ	045ASL	

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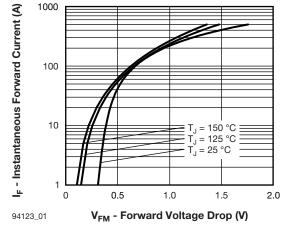


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

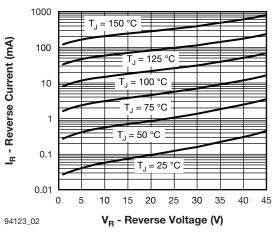


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

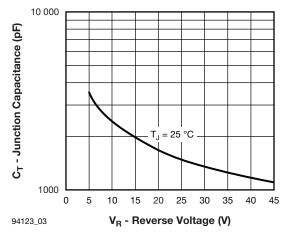
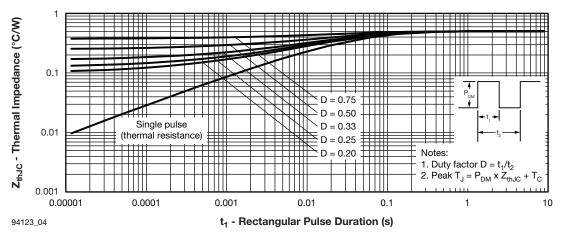


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

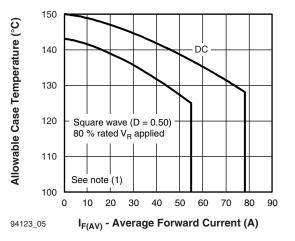




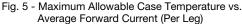
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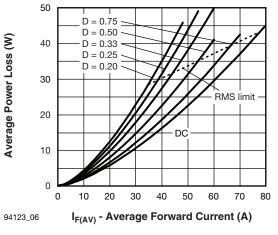


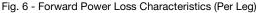
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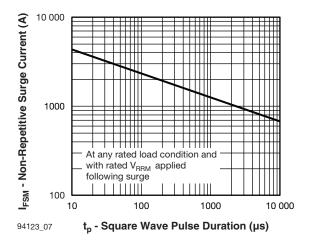


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

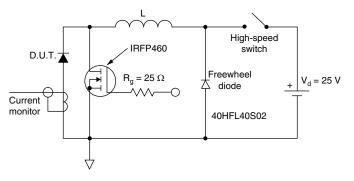


Fig. 8 - Unclamped Inductive Test Circuit

### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

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### **ORDERING INFORMATION TABLE**

Device code	VS-	110	С	N	Q	045	Α	PbF
	1	2	3	4	5	6	7	8
	1 - 2 - 3 - 4 - 5 - 6 - 7 -	Cur Circ C = Pac N = Sch Volt Pac • A s	nay Sem rent ratin uit confi commo kage: D-61 ottky "Q age ratin kage sty = D-61-8 SM = D-1-8 SM = D-1-8	ng (110 guration n cathoo " series ng (045 /le: 3 51-8-SIV	etors pro = 110 A : de = 45 V)	oduct	)	)
	8 -		one = sta oF = lead	-		on		

Standard pack quantity: A = 10 pieces; ASM/ASL = 20 pieces

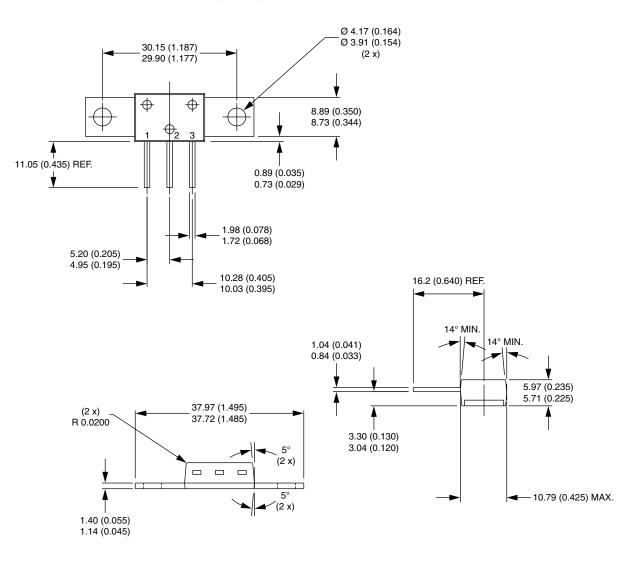
LINKS TO RELATED DOCUMENTS						
Dimensions www.vishay.com/doc?95354						
Part marking information	www.vishay.com/doc?95356					

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D-61-8, D-61-8-SM, D-61-8-SL

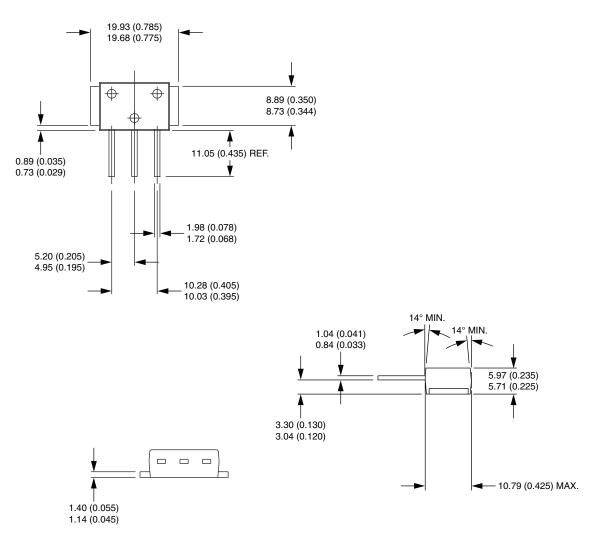
### DIMENSIONS - D-61-8 in millimeters (inches)





### DIMENSIONS - D-61-8-SM in millimeters (inches)

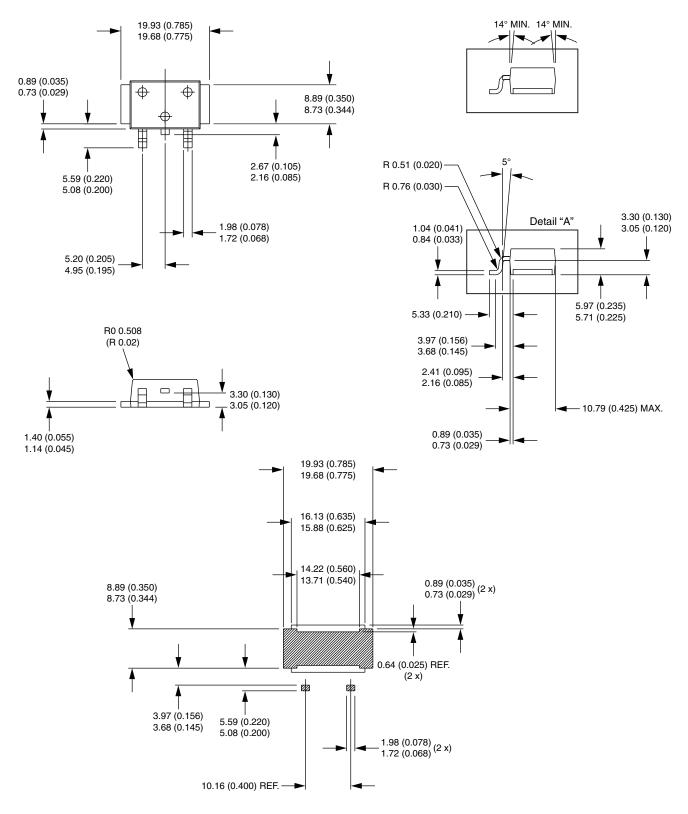
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## DIMENSIONS - D-61-8-SL in millimeters (inches)

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